

Appl. No. 09/653,156

**In the Claims**

Please replace claims 1 and 2 with the following clean version of the amended claims, in accordance with 37 C.F.R. 1.121(c)(1)(i). Please cancel claims 16-26. Also, cancel all previous versions of any amended claim.

A marked up version showing amendments to any claims being changed is provided in one or more accompanying pages separate from this amendment in accordance with 37 C.F.R. 1.121(c)(1)(ii). Any claim not accompanied by a marked up version has not been changed relative to the immediate prior version, except that marked up versions are not being supplied for any added claim or canceled claim.

---

1. (once amended) A capacitor fabrication method comprising:

forming a first capacitor electrode comprising TiN over a substrate, the first electrode having an inner surface area per unit area and an outer surface area per unit area that are both greater than an outer surface area per unit area of the substrate;

forming a capacitor dielectric layer over the first electrode; and

forming a second capacitor electrode over the dielectric layer.

*Sub 3* *Sub 2* (once amended) The method of claim 1 wherein the first electrode consists of TiN. | D

---